

Elektroniikkasuunnittelun perusteet (Principles of electronic design 521431A)
 Exam 16.12.2005

1. a) Calculate amplification and lower corner frequency of the circuit shown in fig 1 a).
 b) Design using an operation amplifier a circuit, which has:
 $R_{in} = 1 \text{ k}\Omega$ and amplification $A = -20$.
 c) Draw the output signal u_o vs. time of the circuit shown in fig 1 b) in a same figure with the input signal u_i .

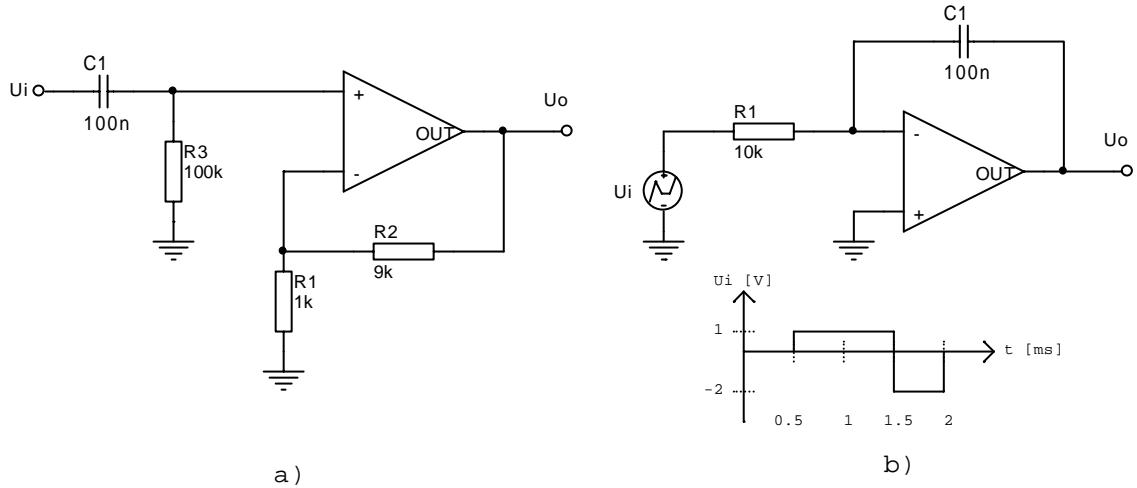


Fig 1.

2. Design a circuit using diodes, resistors and DC-voltage sources, which limits the input signal in fig 2. to level $+4V$ / $-5V$. (voltage across forward-biased diode is $0.7V$)

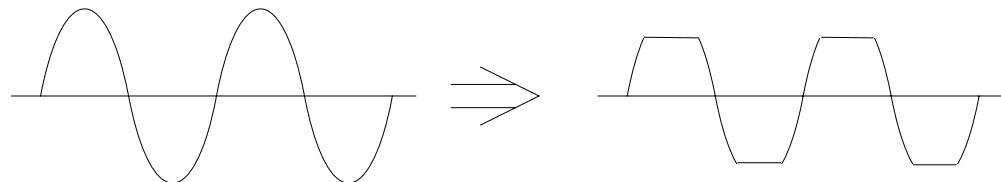


Fig 2.

3. Calculate following parameters from the circuit shown in Fig 3.
- I_C , U_C , U_B and U_E (DC-values)
 - u_o/u_i , R_{in} and R_{out} (you can assume $\beta \gg$, but when calculating R_{in} use $\beta=100$)
- BONUS: Draw u_C ja u_O (total signals) to same figure vs. time.

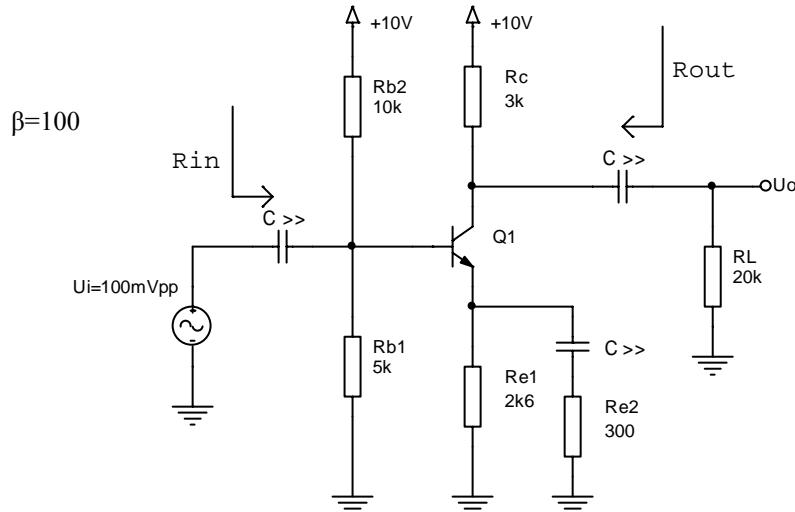


Fig 3.

4. a) Design and draw 2-input NAND-gate using $0.35\mu\text{m:n}$ CMOS-technology.
 (design = choose W and L for transistors and explain your choice.)
 b) What would be the switching threshold voltage, if $V_{DD} = 3\text{V}$?
 c) How much is the propagation delay (to the level 50%) when $C_L = 10\text{ pF}$?

$$U_{tn} = U_{tn} = 0.8\text{ V}$$

$$\mu_n C_{ox} = 100\text{ }\mu\text{AV}^{-2}$$

$$\mu_p C_{ox} = 50\text{ }\mu\text{AV}^{-2}$$

$$r_{ds} \approx \frac{1}{\mu_n C_{ox} \left(\frac{W}{L} \right) (u_{GS} - U_t)}$$

$$t_d \approx 0.7 \cdot RC$$